



SANYO Semiconductors

DATA SHEET

An ON Semiconductor Company

TIG064E8

— N-Channel IGBT
Light-Controlling Flash Applications

Features

- Low-saturation voltage
- Enhancement type
- Mounting Height 0.9mm, Mounting Area 8.12mm²
- Halogen free compliance
- Low voltage drive (2.5V)
- Built-in Gate-to-Emitter protection diode
- dv / dt guarantee*

Specifications

Absolute Maximum Ratings at Ta=25°C

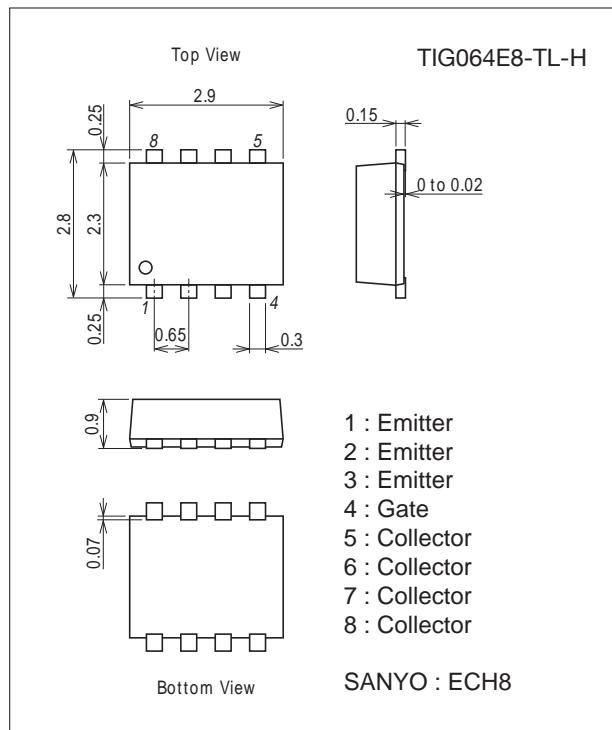
Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Emitter Voltage	V _{CES}		400	V
Gate-to-Emitter Voltage (DC)	V _{GES}		±4	V
Gate-to-Emitter Voltage (Pulse)	V _{GES}	PW≤1ms	±5	V
Collector Current (Pulse)	I _{CP}	V _{GE} =2.5V, C _M =100μF	150	A
Maximum Collector-to-Emitter dv / dt	dV _{CE} / dt	V _{CE} ≤320V, starting T _{ch} =25°C	400	V / μs
Channel Temperature	T _{ch}		150	°C
Storage Temperature	T _{stg}		-40 to +150	°C

* : Concerning dv / dt (slope of Collector Voltage at the time of Turn-OFF), dv / dt > 400V / μs will be 100% screen-detected in the circuit shown as Fig. 1.

Package Dimensions

unit : mm (typ)

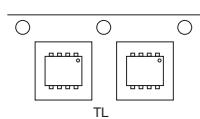
7011A-004



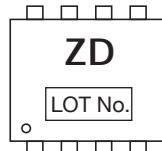
Product & Package Information

- Package : ECH8
- JEITA, JEDEC : -
- Minimum Packing Quantity : 3000 pcs./reel

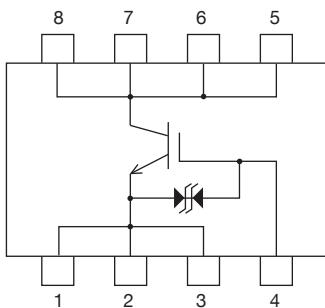
Packing Type: TL



Marking



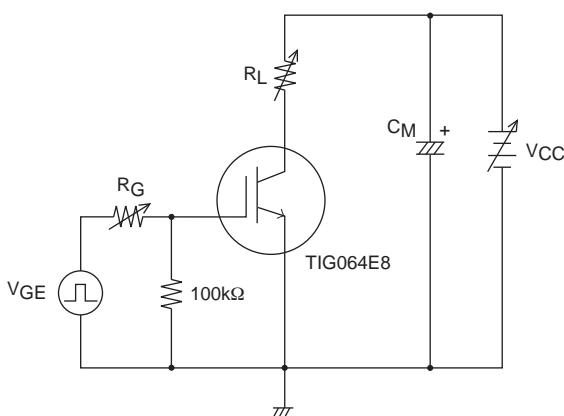
Electrical Connection



Electrical Characteristics at $T_a=25^\circ C$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CES}$	$I_C=2\text{mA}, V_{GE}=0\text{V}$	400			V
Collector-to-Emitter Cutoff Current	I_{CES}	$V_{CE}=320\text{V}, V_{GE}=0\text{V}$			10	μA
Gate-to-Emitter Leakage Current	I_{GES}	$V_{GE}=\pm 4\text{V}, V_{CE}=0\text{V}$			± 10	μA
Gate-to-Emitter Threshold Voltage	$V_{GE(\text{off})}$	$V_{CE}=10\text{V}, I_C=1\text{mA}$	0.4		0.9	V
Collector-to-Emitter Saturation Voltage	$V_{CE(\text{sat})}$	$I_C=100\text{A}, V_{GE}=2.5\text{V}$		4.2	7	V
Input Capacitance	C_{ies}	$V_{CE}=10\text{V}, f=1\text{MHz}$		3100		pF
Output Capacitance	C_{oes}			30		pF
Reverse Transfer Capacitance	C_{res}			23		pF

Fig.1 Large Current R Load Switching Circuit

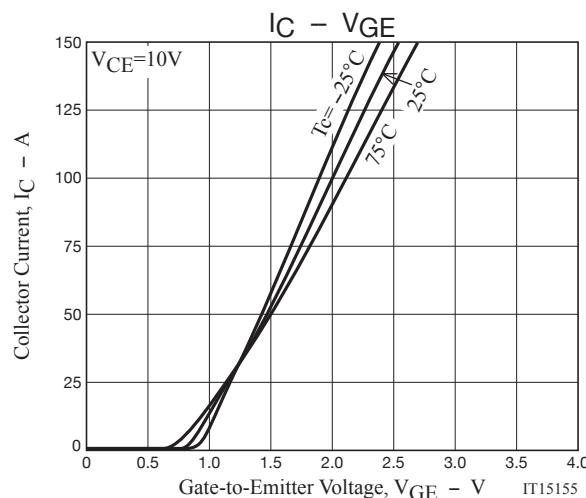
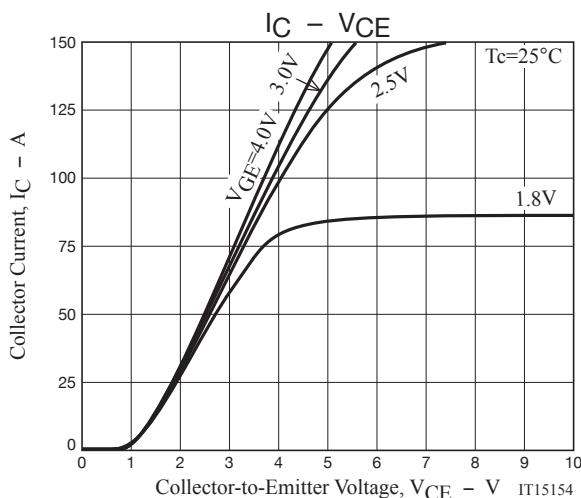


Note1. Gate Series Resistance $R_G \geq 160\Omega$ is recommended for protection purpose at the time of turn OFF. However, if $dv/dt \leq 400\text{V}/\mu\text{s}$ is satisfied at customer's actual set evaluation, $R_G < 160\Omega$ can also be used.

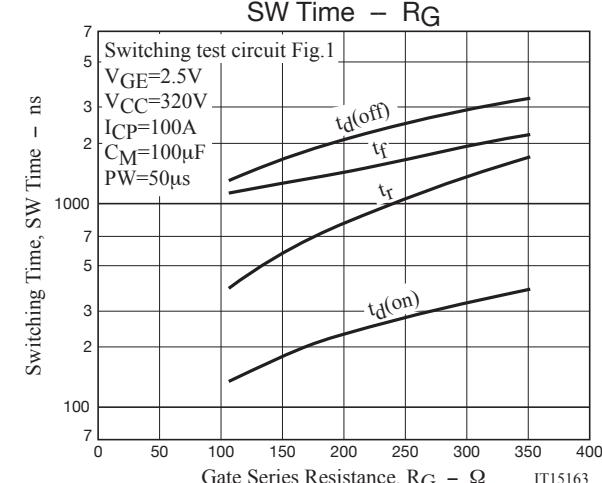
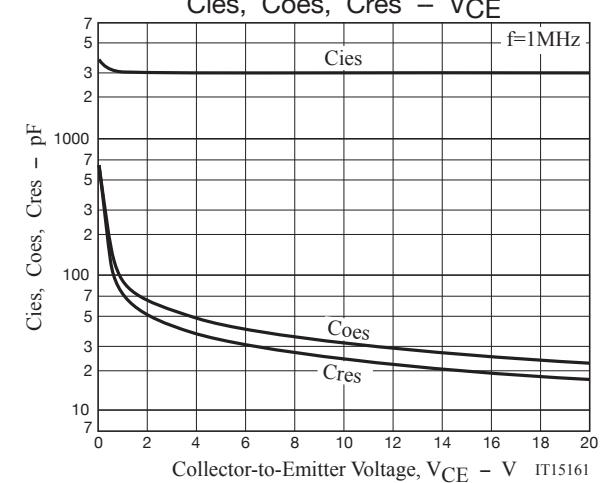
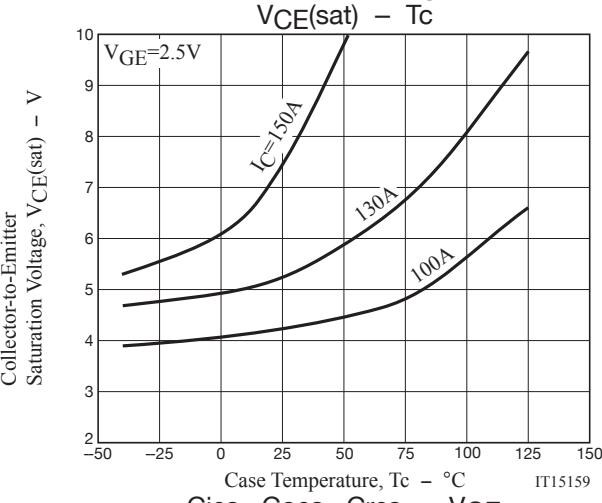
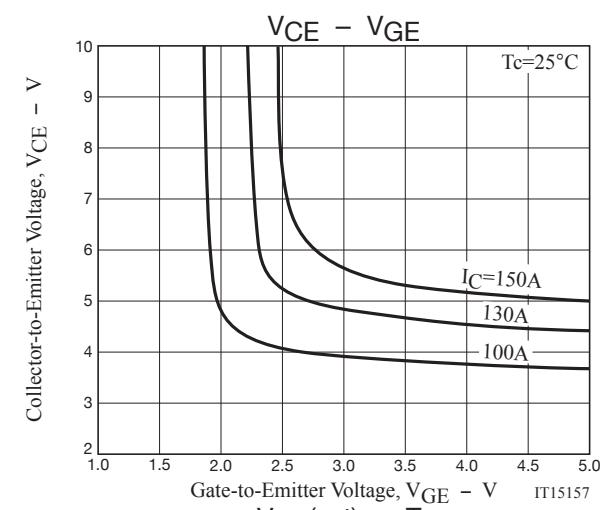
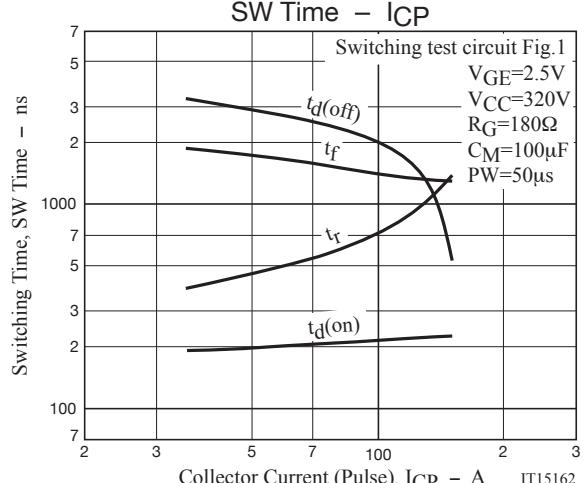
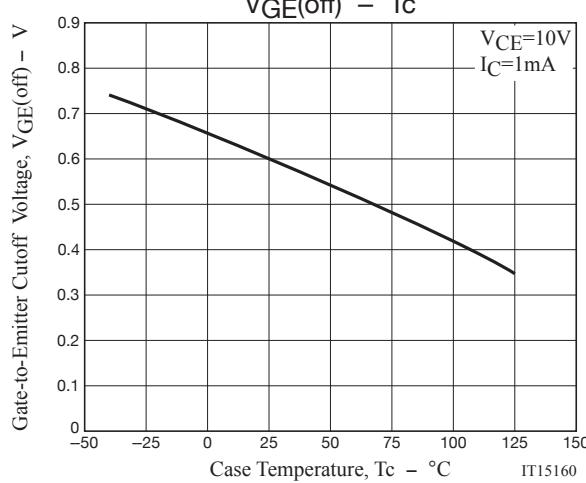
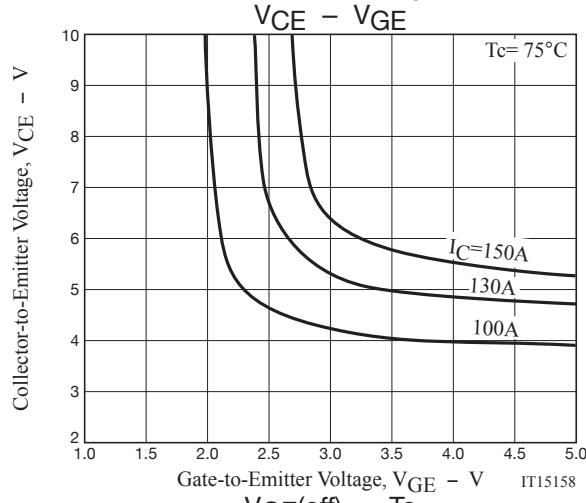
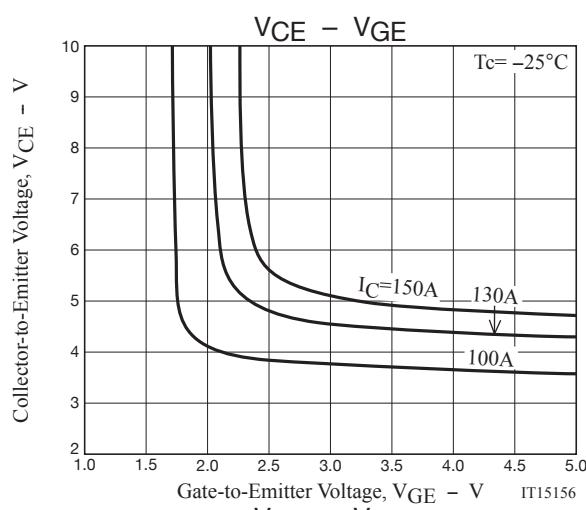
Note2. The collector voltage gradient dv/dt must be smaller than $400\text{V}/\mu\text{s}$ to protect the device when it is turned off.

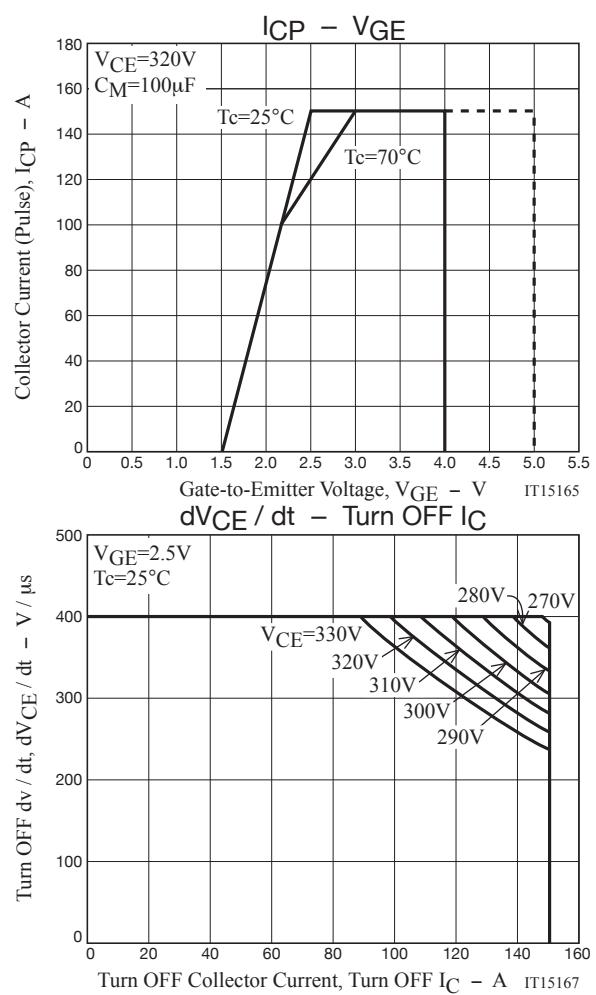
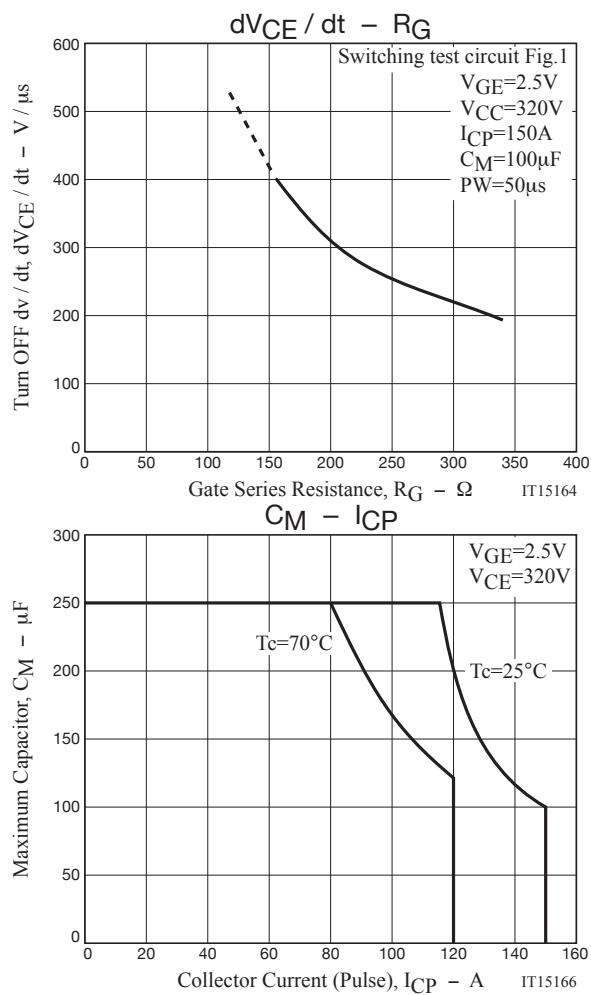
Ordering Information

Device	Package	Shipping	memo
TIG064E8-TL-H	ECH8	3,000pcs./reel	Pb Free and Halogen Free



TIG064E8



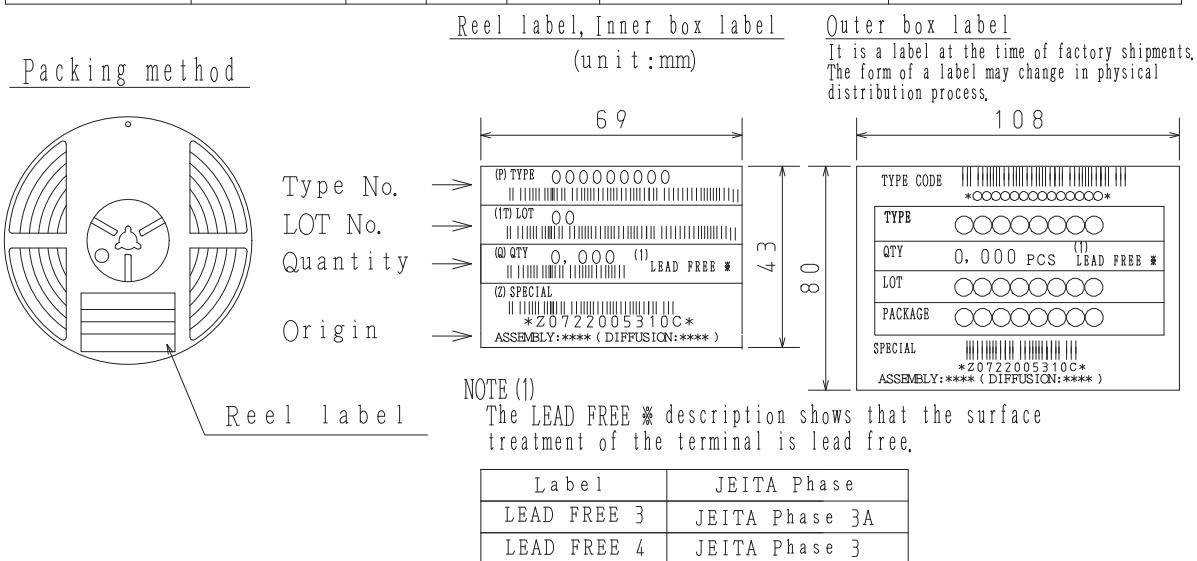


Embossed Taping Specification

TIG064E8-TL-H

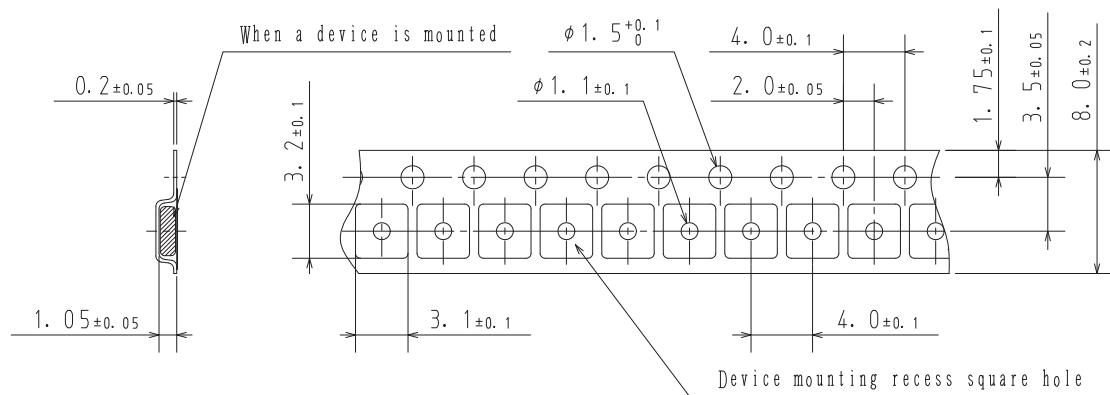
1. Packing Format

Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
ECH8	CPH6	3,000	15,000	90,000	5 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

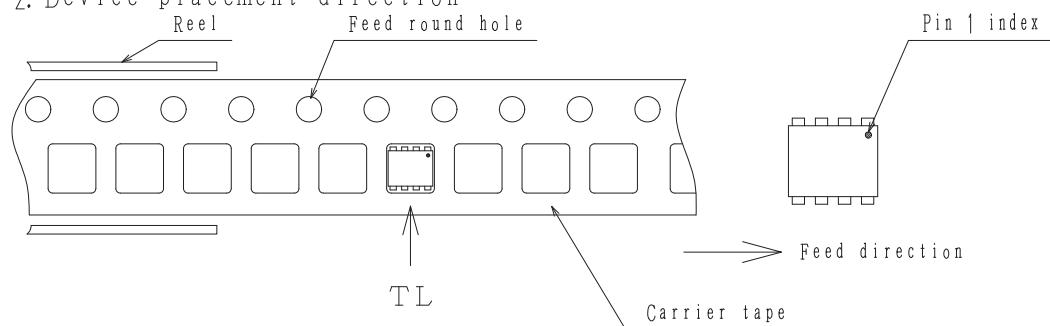


2. Taping configuration

2-1. Carrier tape size (unit:mm)



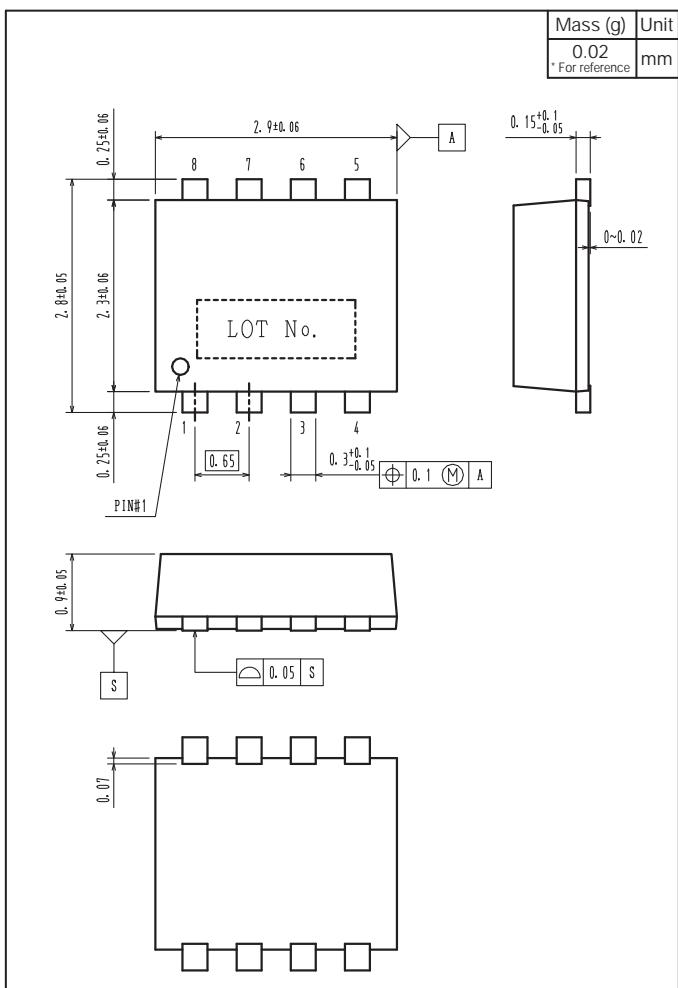
2-2. Device placement direction



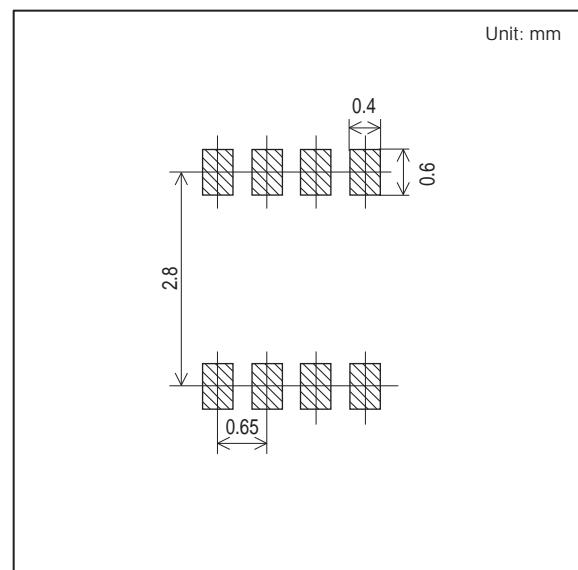
Those with pin 1 index on the feed hole side.....TL

Outline Drawing

TIG064E8-TL-H



Land Pattern Example



Note : TIG064E8 has protection diode between gate and emitter but handling it requires sufficient care to be taken.

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